Strong exciton-photon coupling in open semiconductor microcavities
S. Dufferwiel, F. Fras, A. Trichet, P. M. Walker, F. Li, L. Giriunas, M. N. Makhonin, L. R. Wilson, J. M. Smith, E. Clarke, M. S. Skolnick, and D. N. Krizhanovskii

View online: http://dx.doi.org/10.1063/1.4878504
View Table of Contents: http://scitation.aip.org/content/aip/journal/apl/104/19?ver=pdfcov
Published by the AIP Publishing

Articles you may be interested in
Strong exciton-photon coupling in ZnO based resonators
J. Vac. Sci. Technol. B 27, 1726 (2009); 10.1116/1.3086661

GaN hybrid microcavities in the strong coupling regime grown by metal-organic chemical vapor deposition on sapphire substrates

Strong exciton-photon coupling in a microcavity containing layered perovskite semiconductors

Consequences of strong coupling between excitons and microcavity leaky modes
Appl. Phys. Lett. 86, 071916 (2005); 10.1063/1.1861979

Tuning the exciton-photon coupling in a strongly coupled organic microcavity containing an optical wedge

NEW! Asylum Research MFP-3D Infinity™ AFM
Unmatched Performance, Versatility and Support

Stunning high performance
Comprehensive tools for nanomechanics
Wideest range of accessories for materials science and bioscience
Strong exciton-photon coupling in open semiconductor microcavities

S. Dufferwiel, F. Fras, A. Trichter, P. M. Walker, F. Li, L. Girinunas, M. N. Makhonin, L. R. Wilson, J. M. Smith, E. Clarke, M. S. Skolnick, and D. N. Krizhanovskii

1Department of Physics and Astronomy, University of Sheffield, Sheffield S3 7RH, United Kingdom
2Department of Materials, University of Oxford, Oxford OX1 3PH, United Kingdom
3EPSRC National Centre for III-V Technologies, University of Sheffield, Sheffield S1 3JD, United Kingdom

(Received 6 March 2014; accepted 3 May 2014; published online 14 May 2014)

We present a method to implement 3-dimensional polariton confinement with in-situ spectral tuning of the cavity mode. Our tunable microcavity is a hybrid system consisting of a bottom semiconductor distributed Bragg reflector (DBR) with a cavity containing quantum wells (QWs) grown on top and a dielectric concave DBR separated by a micrometer sized gap. Nanopositioners allow independent positioning of the two mirrors and the cavity mode energy can be tuned by controlling the distance between them. When close to resonance, we observe a characteristic anticrossing between the cavity modes and the QW exciton demonstrating strong coupling. For the smallest radii of curvature concave mirrors of 5.6 µm and 7.5 µm, real-space polariton imaging reveals submicron polariton confinement due to the hemispherical cavity geometry. © 2014 AIP Publishing LLC. [http://dx.doi.org/10.1063/1.4878504]

Strong coupling between quantum well (QW) excitons and photons in a semiconductor microcavity leads to the formation of quasiparticles known as exciton-polaritons. Due to their part-matter part-photon nature, polaritons possess a large nonlinearity arising from exciton-exciton interactions that can be probed through coupling to their photonic component. Recently, microcavity polariton systems have attracted much interest since polaritons exhibit interesting phenomena such as non-equilibrium condensation, superfluid like behaviour, and soliton formation. Conventional semiconductor microcavities are comprised of two semiconductor distributed Bragg reflectors (DBRs) separated by a m/2 cavity containing one or more QWs located at electric-field antinodes. In these monolithic cavities, the spectral features are fixed in energy and in-situ tuning of the cavity mode is limited to tapering of the cavity length along the sample. In an open cavity system, the microcavity is split into three separate parts; a bottom DBR with cavity region, an air gap, and a top DBR. The cavity resonance can then simply be tuned by changing the distance between the mirrors. Open cavity systems have been used to study cavity quantum electrodynamical effects with a variety of emitters.

Due to the low in plane effective mass of polaritons micrometer sized lateral confinement leads to the discretisation of the polariton modes. Smaller confinement causes the average polariton-polariton distance to be reduced and the nonlinear exciton interaction to increase for the same excitation power. Combined with narrow polariton linewidths this lateral confinement may lead to the currently unobserved effect of polariton blockade. Several systems have been developed to achieve zero-dimensional polaritons based on excitonic or photonic confinement. Spatial modulation of the polariton potential has been introduced using cross propagating surface acoustic waves (SAWs) but the confinement size is limited by the small penetration into the microcavity at high SAW frequencies. The application of controlled stress can be used to spatially localise the exciton wavefunction but the energy spectrum remains a quasi-continuum due to weak confinement. Alternatively, photonic confinement can be introduced through the growth of mesa structures using patterned regrowth, post growth etching into micropillars, and photonic crystals. Typically, micropillars and photonic crystal microcavities suffer from increased losses as the dimensions are reduced and in all mentioned cases the spectral tuning of the cavities is limited.

In this Letter, we present a fully tunable zero dimensional polariton system based upon strong photonic confinement in an open hemispherical microcavity. The tuneable cavity consists of a dielectric DBR containing concave features of various radii of curvature (RoC) and a semiconductor DBR with a cavity region containing QWs grown above. The hemispherical cavity geometry leads to strong lateral photonic confinement which is then imprinted in the polariton wavefunction. The combination of both longitudinal and lateral confinement creates photonic confinement in 3-dimensions and leads to the formation of 0-dimensional polaritons.

The dielectric DBR contains an array of concave mirrors fabricated using focused ion beam (FIB) milling before coating with dielectric layers. In contrast to fiber based open microcavities, where the concave feature is fabricated using laser ablation into the end of an optical fiber, FIB milling on a planar substrate allows both the fabrication of smaller RoCs and allows a single sample to contain an array of concave mirrors. We note that laser ablation has also been used to form concave depressions in a planar substrate to fabricate a similar cavity to that described here, rather than using a fiber based approach. Fig. 1(a) shows the set-up of the open cavity system consisting of a top dielectric concave DBR array and a bottom semiconductor DBR with a cavity region containing QWs that are separated by a micron sized gap. The two mirrors were mounted on to two separate xy-zpiezo closed loop attocube nanopositioner stacks allowing full spatial and spectral tuning of the cavity. In this study, we report on experiments using a semiconductor MBE grown 27 paired Al0.85Ga0.15As/GaAs DBR with a cavity region grown on top consisting of two sets of three 10 nm InGaAs QWs...
placed at E-field antinodes using GaAs spacer layers. The dielectric concave mirrors have RoCs of 19 μm, 16 μm, 12 μm, 10 μm, 7.5 μm, and 5.6 μm with the desired RoC mirror placed into the optical path using the xy-stages. For the semiconductor mirror, the piezo stack also consists of two tilt goniometer stages allowing full control of the parallelism between the mirrors. For low temperature measurements at 4 K, the homemade system is placed in a bath cryostat with a small amount of He exchange gas and is securely fastened inside a liquid He dewar. Optical access to the samples is provided via an optical table placed on top of the insert with free space access through an optical window.

For a hemispherical cavity, stable modes are only formed when the stability condition \( L_{\text{phys}} \leq \text{RoC} \) is satisfied,\(^{21}\) where \( L_{\text{phys}} \) is the physical cavity length and must take into account the field penetration into the DBRs. For our composite cavity, the physical length is defined by

\[
L_{\text{phys}} = L + L_{\text{DBR1}} + L_{\text{DBR2}} + L_{\text{QW}}, \tag{1}
\]

where \( L \) is the tunable mirror separation distance as indicated in Fig. 1(a), \( L_{\text{DBR1}} \) and \( L_{\text{DBR2}} \) are the physical field penetration depths into the dielectric and semiconductor DBRs, and \( L_{\text{QW}} \) is the physical length of the cavity-QW containing region. The longitudinal spectral resonances of the cavity are determined by the condition that the round trip phase in the cavity \( \phi(k, L) \) is an integer multiple of \( 2\pi \)

\[
\phi(k, L) = 2kL + \phi_{\text{DBR}}(k) = 2mn, \tag{2}
\]

where \( m \) is an integer, \( k \) is the vacuum wavenumber, and \( L \) is the mirror separation distance. The structural constant \( \phi_{\text{DBR}}(k) \) is the sum of the reflection phases of the top DBR and combined bottom DBR and cavity region and may be calculated using a transfer matrix technique. This formula may be rearranged to allow extraction of the mirror separation \( L \) from the free spectral range \( \Delta \lambda = \lambda_{(m - 1)} - \lambda_{(m)} \) between adjacent longitudinal modes. The usual expression becomes modified to account for the difference in DBR reflection phase \( \Delta \phi_{\text{DBR}} = \phi_{\text{DBR}(m - 1)} - \phi_{\text{DBR}(m)} \) at the two wavelengths of the adjacent longitudinal modes

\[
L = \frac{\Delta \phi_{\text{DBR}}}{2\Delta \lambda} \left( 1 + \frac{\Delta \phi_{\text{DBR}}}{2\pi} \right). \tag{3}
\]

Fig. 1(b) shows a typical photoluminescence (PL) spectrum with the longitudinal cavity mode at a large negative exciton-photon detuning of around \(-22.7\) meV. In this regime, the lower polariton is largely photonic and the optical characteristics of the cavity can be probed. We use non-resonant excitation close to a cavity reflectivity minimum using a 685 nm laser diode. Spectroscopy is performed using a 0.75 m monochromator with a cooled CCD at \(-70^\circ\)C. In addition to the ground longitudinal cavity mode \( I \), we observe a number of higher order transverse modes (labeled II, III, IV, and V) with equal energy spacing due to lateral confinement. This suggests that the transverse photonic potential created by the curved top mirror is nearly parabolic. Fig. 1(c) shows that for a concave mirror of 19 μm, mode I exhibits a splitting between orthogonally polarized modes of \(-110 \) μeV, which probably arises from birefringence in the bottom and/or in the top mirror due to stress. Higher order transverse modes also split into a doublet with an energy splitting of the order of \(-100–200 \) μeV as seen in Fig. 1(b) due to a combination of birefringence and breaking of the cylindrical symmetry in the shape of the top mirror as discussed below.

Fig. 1(d) shows the photonic Q-factor as a function of \( L \) measured for mirrors with different RoC, where \( L \) was deduced from white light reflectivity spectra using Eq. (3). The photonic Q-factor of the microcavity increases with cavity length due to the increased photonic lifetime up to a maximum value of \(-35 \) 000 at \( L = 9 \) μm for the mirror with RoC = 19 μm and 16 μm. The Q-factor then decreases as \( L \) and hence \( L_{\text{phys}} \) increase further. This can be attributed to the diverging beam waist on the concave mirror leading to larger losses as we approach the limits of the stability condition.\(^{20}\) We estimate that the minimum mirror separation before touching that we can reach is \( L \approx 1 \) μm.

In order to spectrally tune the cavity resonance, we apply a DC voltage to the bottom z-piezo nanopositioner which decreases the mirror separation \( L \). By scanning the cavity length in this manner, we tune the cavity modes through resonance with the QW exciton energy. Fig. 2(a) shows the characteristic avoided crossing in PL between the cavity modes and QW exciton. It is clear that both mode I and higher order transverse modes all display an avoided crossing with the exciton resonance. The Rabi splitting \( \Delta \Omega_{\text{Rabi}} \), when mode I is at resonance with the QW exciton at a mirror separation \( L \approx 5 \) μm, is 4.4 meV and is comparable across all modes due to the negligible dependence of the coupling strength with exciton wavevector. Fig. 2(b) shows a spectral slice at zero detuning between mode I and the QW exciton. The confined upper polariton has a weaker PL signal.
as polaritons tend to relax towards the lowest energy states of the trap. The upper polariton is significantly broader than the lower polariton due to scattering with phonons and QW disorder potential to the lower polariton and the exciton reservoir.\textsuperscript{22} At zero exciton-photon detuning at the minimum effective cavity length, we measure a lower polariton linewidth of 1.2 meV and the photonic linewidth is around 78 µeV. At the minimum cavity length, the maximum observed vacuum Rabi splitting at resonance is 5.6 meV, which is comparable to the values obtained in monolithic 6 QW 3/2 microcavities. In Fig. 2(c), we plot the Rabi splitting at zero exciton-photon detuning as a function of L for cavities formed with each of the concave RoCs. The splitting is expected to be inversely proportional to the square root of the cavity effective length $L_{\text{eff}}$, which is given by the ratio of the integrated electric energy density in the cavity divided by the density at the QWs.\textsuperscript{23} At fixed energy $L_{\text{eff}}$ is proportional to $L + C$, where L is the mirror separation and the constant C accounts for the fraction of the mode energy located in the DBRs and QW region. The fit in Fig. 2(c) corresponds to $\Omega_{\text{Rabi}} \propto 1/\sqrt{L + C}$, with $C \approx 7.6 \mu$m. No dependence on the RoC was observed.

To enable imaging of the polariton modes, we employ a wound fiber bundle consisting of a 4 x 4 mm array of single mode fibers. Each single mode fiber in the array acts like a single pixel allowing the image focused on one end of the fiber to be emitted from the other end. We then image the real or k-space image of the polariton on to one end facet and image the other end on to the slits of a spectrometer.

Fig. 3(a) shows position-wavelength images of cavity modes when longitudinal mode I is negatively detuned with respect to the exciton. Here, the emission intensities are plotted for different wavelengths versus position across the line going through the middle of the cavity. These spatial mode profiles correspond to the modes that we display spectrally in Fig. 1(b) at slightly larger negative detuning of $-4.7\Omega_{\text{Rabi}} = -24.4$ meV and provide direct evidence of the micrometer sized confinement and spatial discretization of modes. Fig. 3(b) shows the position-wavelength images of polariton modes when the mode I is close to resonance with the QW exciton. Here, we can clearly see the imprinting of the photonic spatial distribution into the polariton modes $UP_I$ and $LP_I$ and $UP_{II}$ and $LP_{II}$. Modes $UP_I$ and $LP_I$ are characterised by Gaussian spatial distribution, whereas modes $UP_{II}$ and $LP_{II}$ have two distinct maxima at $\pm 1 \mu$m. For the longitudinal mode I, we measure a Gaussian beam waist size of 1.16 µm on the concave mirror with RoC = 19 µm at $L \approx 1.7 \mu$m. For the RoCs of 7.5 µm and 5.6 µm, we measure beam waist sizes of 0.85 µm and 0.78 µm—better than the confinement achieved in mesa\textsuperscript{17} or micropillar\textsuperscript{18} structures. We note that the beam waist size on the planar semiconductor part is slightly smaller than the beam waist on the concave mirror when $L_{\text{phys}} \ll \text{RoC.}^\text{21}$

The inset in Fig. 3 shows the real space PL images of photonic modes revealing profiles for modes I, II, III, and IV, which resemble helical Laguerre-Gaussian (LG) transverse modes. Formation of such modes is expected in a system with perfect cylindrical symmetry.\textsuperscript{24} Nevertheless, spectrally resolved images reveal that LG in our system actually are not the eigenstates and are split into a family of Mathieu and Ince-Gaussian modes\textsuperscript{25} probably due to breaking of the cylindrical symmetry of the top mirror. The detailed investigation of this effect is beyond the scope of the present manuscript and will be presented elsewhere.
In summary, we present a system to achieve 3-dimensional polariton confinement with \textit{in situ} tuning of the cavity modes. When the cavity is formed with concave DBRs with RoCs of 7.5 \textmu m and 5.6 \textmu m, we measure submicron polariton beam waist sizes. Combining the submicron confinement with very narrow lower polariton linewidths has the potential to lead to strong nonlinear interactions between polaritons and the observation of the polariton blockade effect\textsuperscript{12} in single or coupled polariton boxes.\textsuperscript{26,27}

This work has been supported by the EPSRC Programme Grant EP/J007544, ERC Advanced Investigator Grant EXCIPOL, and by the Leverhulme Trust.


\textsuperscript{23}A. V. Kavokin, J. J. Baumberg, G. Malpuech, and F. P. Laussy, \textit{Microcavities, Series on Semiconductor Science and Technology} (Oxford University Press, 2007).


